NSN 5961-00-929-1262

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-929-1262 **Inclosure Material:** Glass **Overall Length:** 0.188 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.100 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 peak-point voltage **Current Rating Per Characteristic:** 500.00 amperes source cutoff current preset and 2.50 amperes source cutoff current absolute **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 250.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: